

300mA Adjustable Output Voltage CMOS LDO Regulator

General Description

The RP1222 is designed for portable RF and wireless applicaiton with demanding performance and space requirements. The RP1222 performance is optimized for battery-powered systems to deliver low noise and low quiescent current. Regulator ground current increase only slightly in dropout, further prolonging the battery life. The RP1222 also works with low-ESR ceramic capacitors, reducing the amount of board space necessary for power applications, ciritical in hand-held wireless devices. The RP1222 has soft start time typical 1300µs. The other features include ultra low dropout voltage, current limiting protection, and high ripple rejection ratio. Available in the 5-lead of SOT-23 package.

Features

- Adjustable Output Voltage
- Ultra-Fast Response in Line/Load Transient
- Long Soft Start Time for Low Inrush Current (Typically 1300µs)
- < 0.1µA Standby Current When Shutdown
- Low Dropout : 220mV @ 300mA
- Wide Operating Voltage Ranges : 2.5V to 5.5V
- TTL-Logic-Controlled Shutdown Input
- Low Temperature Coefficient
- Current Limiting Protection
- Thermal Shutdown Protection
- Only 1µF Output Capacitor Required for Stability
- High Power Supply Rejection Ratio
- RoHS Compliant and 100% Lead (Pb)-Free

Ordering Information

RP1222□□□	
	Package Type
	B : SOT-23-5
	Operating Temperature Range
	G : Green (Halogen Free with Commercial Standard)
	Output Voltage
	A : High Enable without Discharge
	B : High Enable with Discharge
	C : Low Enable without Discharge
	D : Low Enable with Discharge

Note :

Richpower Green products are :

- ▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

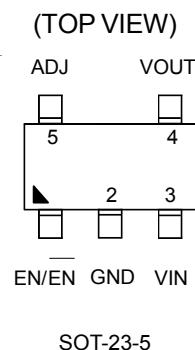
Marking Information

For marking information, contact our sales representative directly or through a Richpower distributor located in your area.

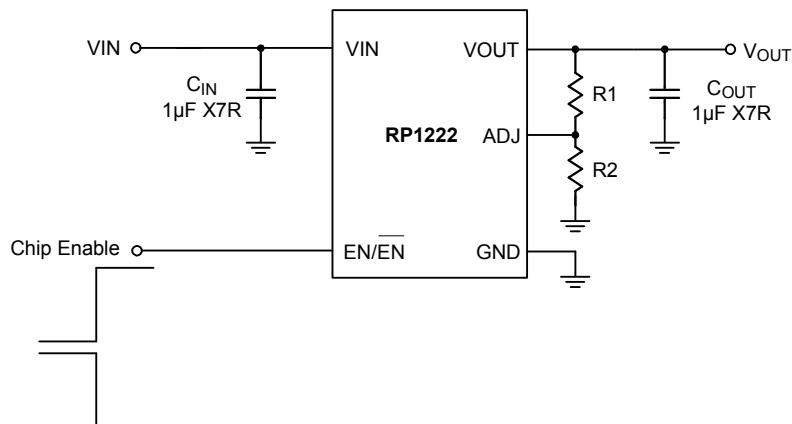
Applications

- Power source for battery-powered equipment
- Power source for cameras, camcorders, VCRs, PDAs, pagers, electronic data banks, and hand-held communication equipment
- Power source for appliances, which require higher voltage than that of batteries used in the appliances

Pin Configurations



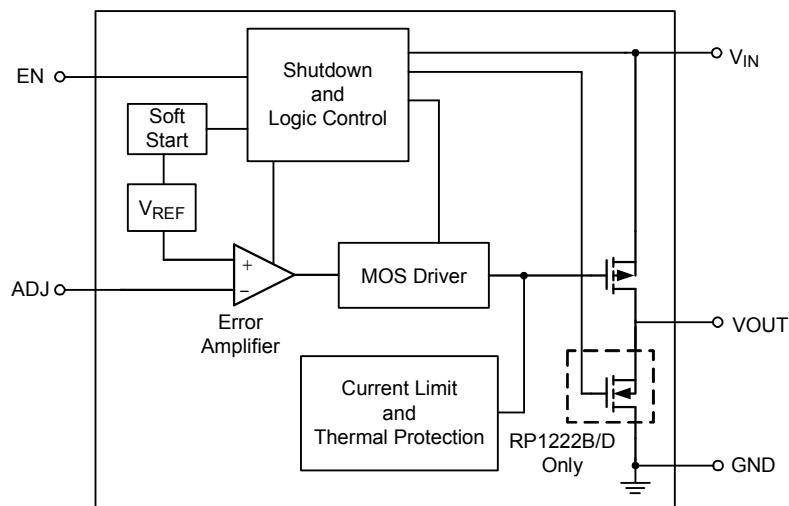
Typical Application Circuit



Functional Pin Description

Pin NO.	Pin Name	Pin Function
1	EN/EN	Chip Enable (Active High/Low). Note that this pin is high impedance. There should be a pull low/high 100kΩ resistor connected to GND/VIN when the control signal is floating.
2	GND	Ground.
3	VIN	Power Input Voltage.
4	VOUT	Output Voltage.
5	ADJ	Adjust Output.

Function Block Diagram



Absolute Maximum Ratings (Note 1)

- Supply Voltage (V_{IN}) ----- -0.3V to 6V
- Chip Enable Input Voltage (V_{EN}) ----- -0.3V to 6V
- Output Voltage (V_{OUT}) ----- -0.3V to $V_{OUT} + 0.3V$
- Adjust Output (V_{ADJ}) ----- -0.3V to $V_{OUT} + 0.3V$
- Power Dissipation, P_D @ $T_A = 25^\circ C$
SOT-23-5 ----- 0.4W
- Package Thermal Resistance (Note 4)
SOT-23-5, θ_{JA} ----- 250°C/W
- Operating Temperature Range ----- -40°C to 85°C
- Storage Temperature Range ----- -65°C to 150°C
- Lead Temperature (Soldering, 10 sec.) ----- 260°C
- ESD Susceptibility (Note 2)
HBM (Human Body Mode) ----- 2kV
MM (Machine Mode) ----- 200V

Recommended Operating Conditions (Note 3)

- Supply Voltage V_{IN} ----- 2.4V to 5.5V
- Junction Temperature Range ----- -40°C to 125°C

Electrical Characteristics

($V_{IN} = V_{OUT} + 1V$, $C_{IN} = C_{OUT} = 1\mu F$, $T_A = 25^\circ C$, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Input Voltage Range	V_{IN}		2.4	--	5.5	V
ADJ Reference Voltage	V_{ADJ}	$V_{IN} = 5V$, $I_{OUT} = 100mA$	0.788	0.8	0.812	V
Current Limit	I_{LIM}	$R_{OUT} = 1\Omega$	360	--	650	mA
Quiescent Current	I_Q	$I_{OUT} = 0mA$	--	120	160	μA
Dropout Voltage	V_{DROP}	$I_{OUT} = 200mA$, $V_{OUT} > 2.8V$	--	170	200	mV
		$I_{OUT} = 300mA$, $V_{OUT} > 2.8V$	--	220	300	mV
Line Regulation	ΔV_{LINE}	$V_{IN} = (V_{OUT} + 1V) > 2.8V$ $I_{OUT} = 1mA$	--	--	0.3	%
Load Regulation	ΔV_{LOAD}	$1mA < I_{OUT} < 300mA$	--	--	0.6	%
Standby Current	I_{STBY}	$V_{EN} = GND$ or Shutdown	--	0.01	1	μA
EN Input Bias Current	I_{IBSD}	$V_{EN} = GND$ or V_{IN}	--	0	100	nA
EN/ \overline{EN} Threshold	V_{IL}		--	--	0.4	V
	V_{IH}		1.2	--	--	V

To be continued

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Soft Start Time	T _{SS}	V _{OUT} Rising from 10% to 90%	800	1300	1800	μs
Under-Voltage Lockout	V _{UVLO}	V _{IN} Rising	2.0	2.2	2.4	V
Under-Voltage Lockout Hysteresis	ΔV _{UVLO}	V _{IN} Falling	0.12	0.2	--	V
Thermal Shutdown Temperature	T _{SD}		125	165	--	°C
Hysteresis	ΔT _{SD}		--	30	--	°C

Note 1. Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

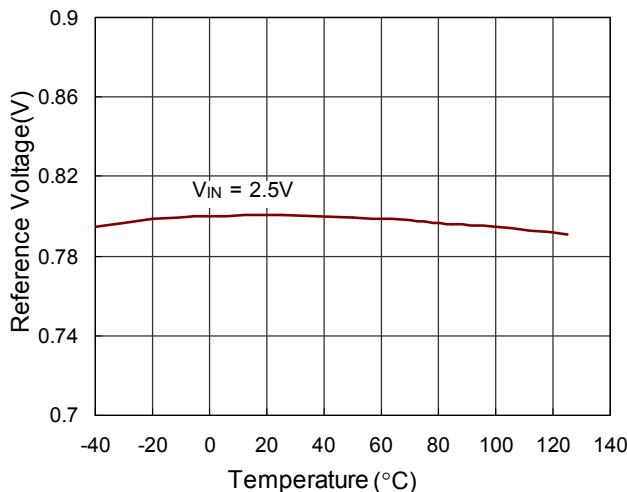
Note 2. Devices are ESD sensitive. Handling precaution recommended.

Note 3. The device is not guaranteed to function outside its operating conditions.

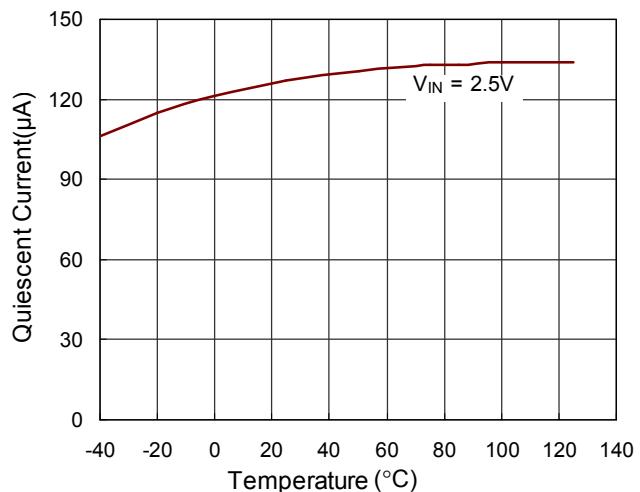
Note 4. θ_{JA} is measured in the natural convection at T_A = 25°C on a low effective thermal conductivity test board (Single Layer, 1S) of JEDEC 51-3 thermal measurement standard.

Typical Operating Characteristics

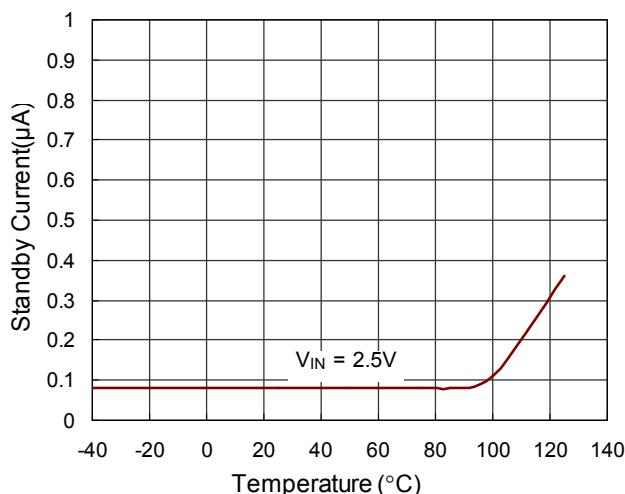
Reference Voltage vs. Temperature



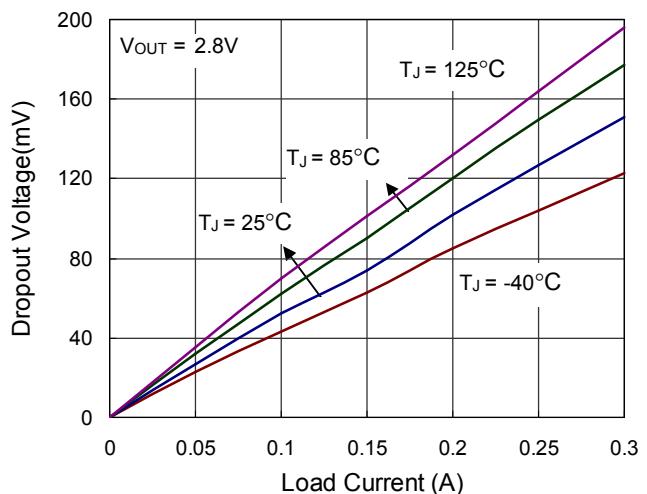
Quiescent Current vs. Temperature



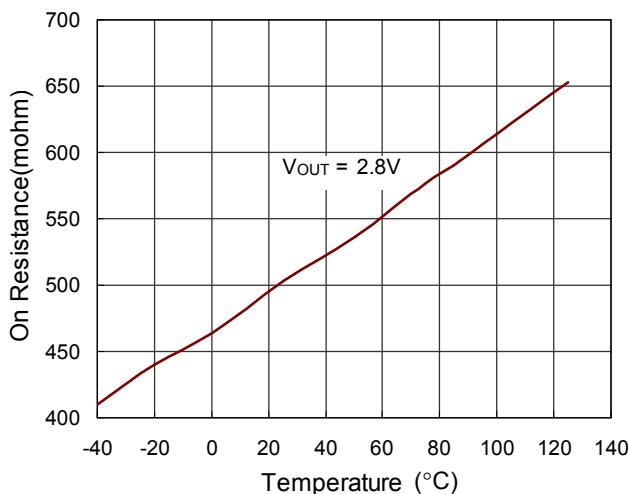
Standby Current vs. Temperature



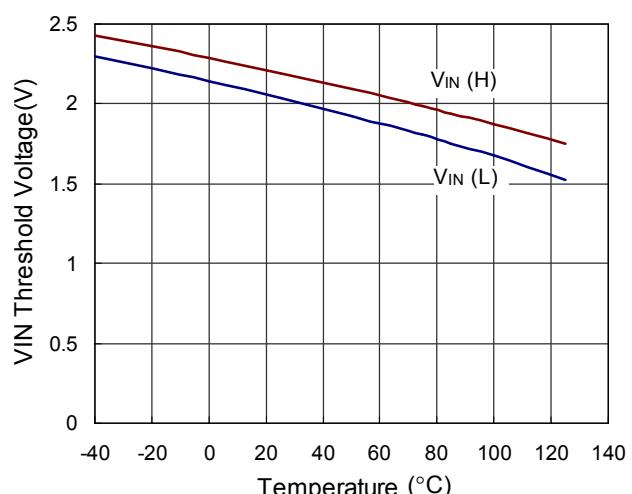
Dropout Voltage vs. Load Current

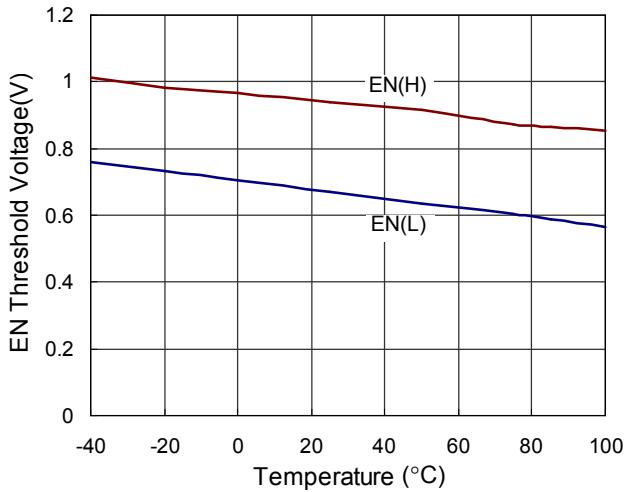
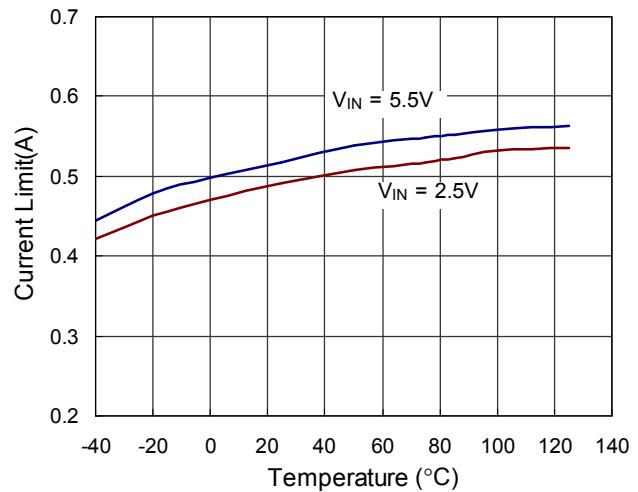
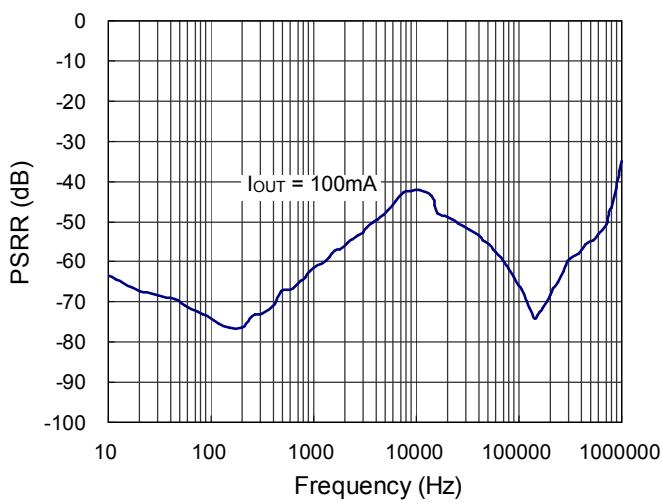
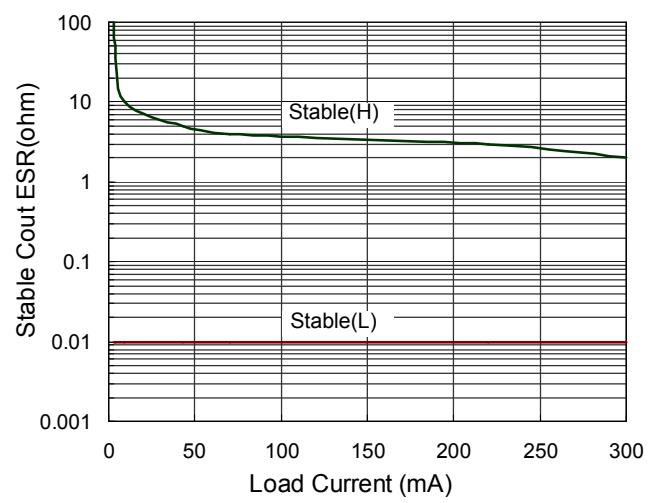
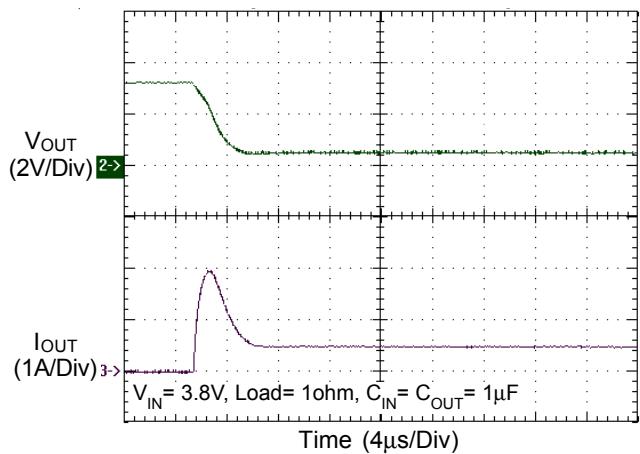
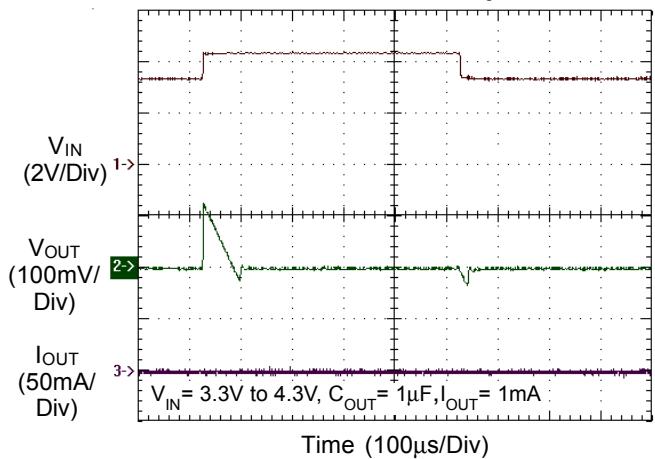


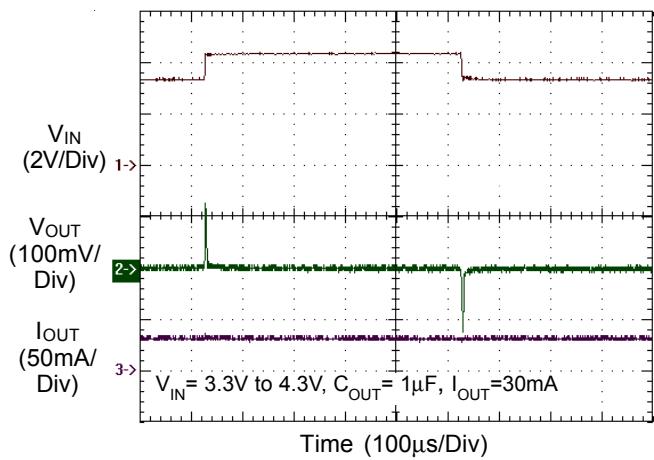
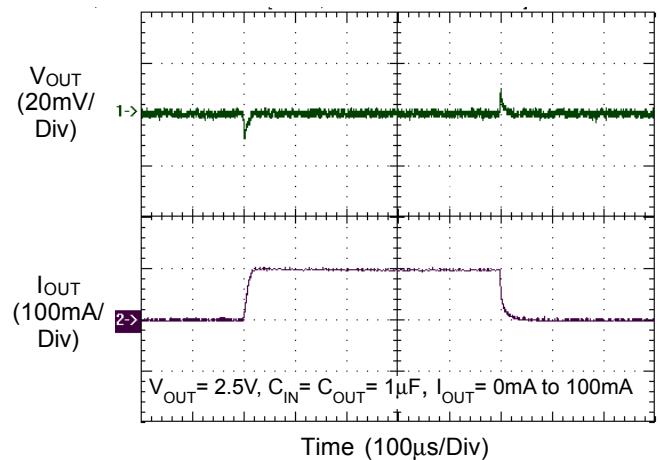
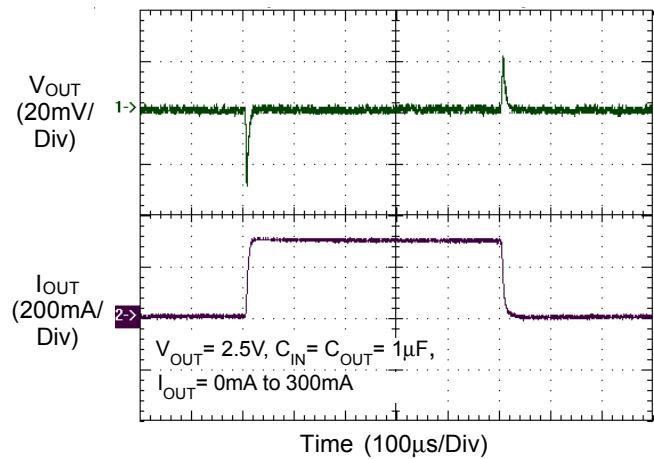
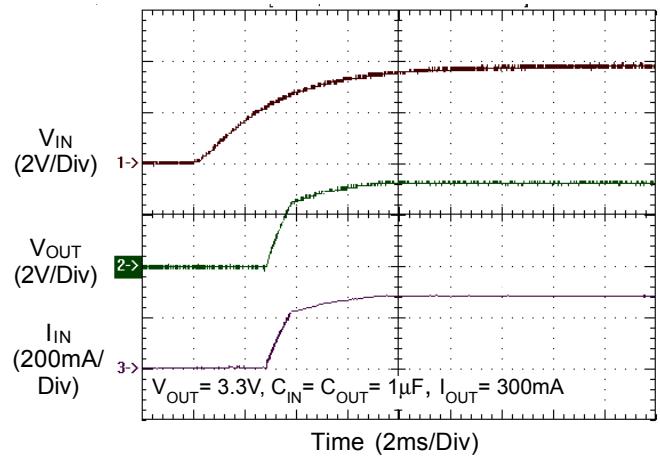
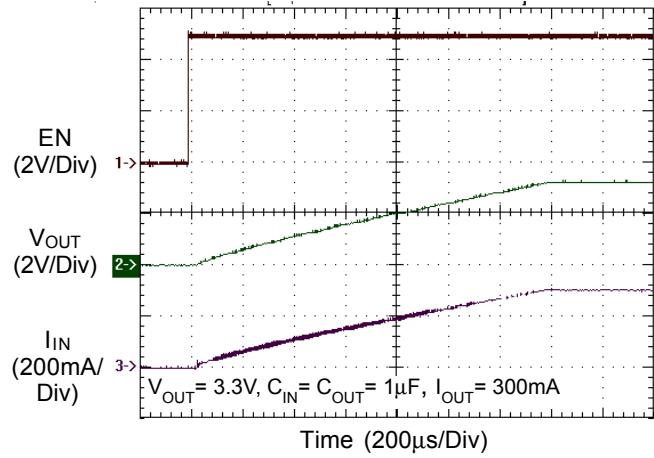
On Resistance vs. Temperature



V_{IN} Threshold Voltage vs. Temperature



Enable Threshold Voltage vs. Temperature**Current Limit vs. Temperature****PSRR****Stable Cout ESR vs. Load Current****Current Limit Response****Line Transient Response**

Line Transient Response**Load Transient Response****Load Transient Response****Power On Response****Turn On Response**

Application Information

The RP1222 requires input and output decoupling capacitors. These capacitors must be correctly selected for good performance and insufficient decoupling capacitance may cause oscillation.

Input Capacitor

Use a capacitor with value $\geq 1\mu\text{F}$ on the RP1222 input and the amount of capacitance can be increased without limit. The input capacitor must be placed within 1cm from the device to assure input stability. There are no requirements for the ESR (equivalent series resistance) on the input capacitor, but low-ESR ceramic capacitor with larger value provides better PSRR and line transient response.

Output Capacitor

The output capacitor must meet both requirements for minimum amount of capacitance and ESR in all applications. The recommended output capacitor type is ceramic capacitor (temperature characteristics X7R or X5R) and capacitance range is from $0.1\mu\text{F}$ to $10\mu\text{F}$ (typical $1\mu\text{F}$) with $\text{ESR} > 25\text{m}\Omega$ for transient stability. However, in some application which low output voltage is required (lower than 1.8V), it is recommended that the maximum output capacitor is not larger than $1\mu\text{F}$ (As to ESR, please refer to Stable C_{OUT} ESR vs. Load Current).

Adjustable Output Voltage

The output voltage is set by the ratio of two external resistors as:

$$V_{\text{OUT}} = 0.8 \times \left(1 + \frac{R_1}{R_2}\right) \text{Volts}$$

Note: The recommended R_2 is $20\text{k}\Omega$ to $100\text{k}\Omega$, and $80\text{k}\Omega$ is preferred.

No Load Stability

The device will remain stable and in regulation with no external load. This is important in CMOS RAM keep-alive applications.

Dropout Voltage

A LDO's minimum input-to-output voltage difference (dropout voltage) determines the lowest usable supply voltage. In battery-powered systems, this determines the useful end-of-life battery voltage. Because the RP1222 uses a PMOS as pass element, its dropout voltage is a

function of drain-to-source on-resistance, $R_{\text{DS(ON)}}$, multiplied by the load current :

$$V_{\text{DROPOUT}} = V_{\text{IN}} - V_{\text{OUT}} = R_{\text{DS(ON)}} \times I_{\text{OUT}}$$

Enable Function

The RP1222 features an enable/disable function. There are high-active and low-active options in this function. In high-active option, the enable control level must be greater than 1.2 volts to turn on the device. The LDO will be shut down when the voltage on the EN pin falls below 0.4 volts and reduces its quiescent current to less than $1\mu\text{A}$. If the enable function is not needed in a specific application, it should be tied to VIN to keep the LDO in a continuous on state.

Current Limit

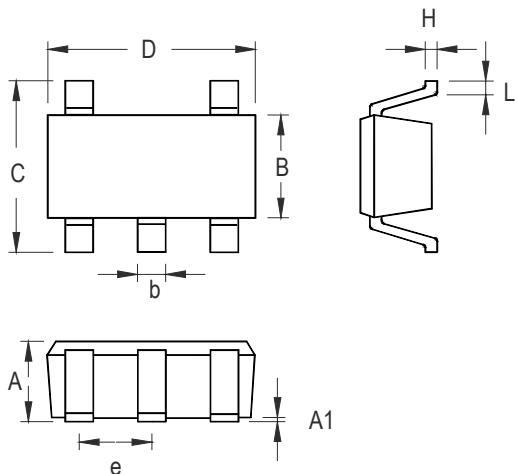
The RP1222 equips an over-current protection function to avoid large output current drain due to abnormalities. It monitors the output current and controls the PMOS' gate voltage, limiting the output current to minimum 650mA. The output can be shorted to ground for an indefinite period of time without damaging the part.

Over Temperature Protection

The RP1222 has an over-temperature protection function to limit the maximum power dissipation. When the operation junction temperature exceeds 165°C , the OTP circuit will turn off the pass element. The pass element turns on again after the junction temperature cools below 135°C . For continue operation, the junction temperature should not exceed absolute maximum operation junction temperature 125°C . The power dissipation definition in device is:

$$P_D = (V_{\text{IN}} - V_{\text{OUT}}) \times I_{\text{OUT}} + V_{\text{IN}} \times I_Q$$

Outline Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.889	1.295	0.035	0.051
A1	0.000	0.152	0.000	0.006
B	1.397	1.803	0.055	0.071
b	0.356	0.559	0.014	0.022
C	2.591	2.997	0.102	0.118
D	2.692	3.099	0.106	0.122
e	0.838	1.041	0.033	0.041
H	0.080	0.254	0.003	0.010
L	0.300	0.610	0.012	0.024

SOT-23-5 Surface Mount Package

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